

TECHNICAL DATA DATA SHEET 4642, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 200 VOLT, 45 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25$ °C UNLESS OTHERWISE SPECIFIED.

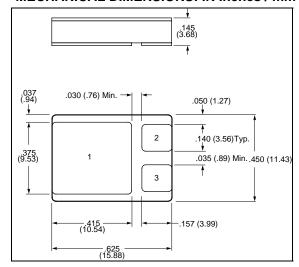
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RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Single)	Io	45	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	1800	pF
MAXIMUM THERMAL RESISTANCE	R _{eJC}	0.25	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 200	°C

ELECTRICAL CHARACTERISTICS

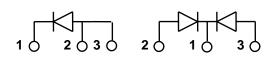
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 45 Amps)			
T _J = 25 °C	V_{f}	1.00	Volts
T _J = 125°C		0.80	
MAXIMUM REVERSE CURRENT (I _r @ 200 V PIV)			
T _J = 25 °C	l _r	2.1	mA
T _J = 125 °C		48	

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MECHANICAL DIMENSIONS: IN Inches / mm





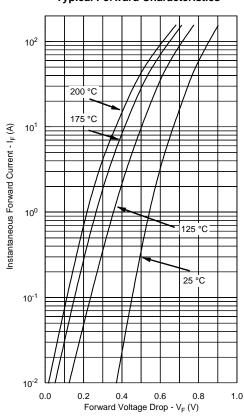


LCC-3P

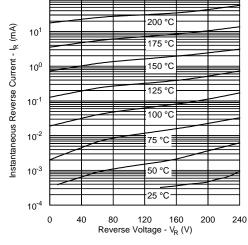
PINOUT TABLE

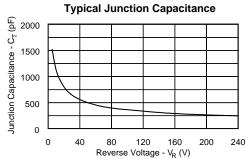
DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

Typical Forward Characteristics



Typical Reverse Characteristics







TECHNICAL DATA

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